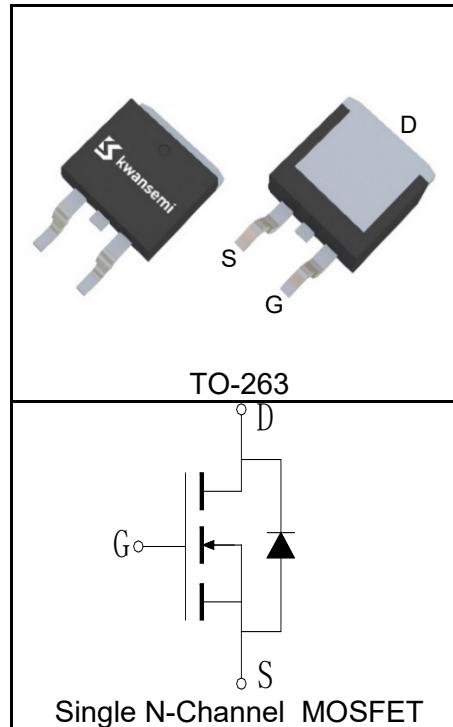


## Features

- 100V/273A,
- $R_{DS(on)} = 2\text{m}\Omega(\text{Typ.}) @ V_{GS} = 10\text{V}$
- Excellent  $Q_G \times R_{DS(on)}$  product(FOM)
- SGT Technology
- High Ruggedness
- 100% Avalanche Tested

## Pin Description



## Applications

- Motor Control
- Battery Power Management



Halogen-Free

## Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
<b>Common Ratings</b> ( $T_c = 25^\circ\text{C}$ Unless Otherwise Noted)			
$V_{DSS}$	Drain-Source Voltage	100	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	
$T_{Jmax}$	Maximum Junction Temperature	175	$^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
$I_S$	Diode Continuous Forward Current	$T_c = 25^\circ\text{C}$	A
<b>Mounted on Large Heat Sink</b>			
$I_{DP}^{(1)}$	Pulse Drain Current	$T_c = 25^\circ\text{C}$	A
$I_D^{(2)}$	Continuous Drain Current( $V_{GS} = 10\text{V}$ )	$T_c = 25^\circ\text{C}$	A
		$T_c = 100^\circ\text{C}$	
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ\text{C}$	W
		$T_c = 100^\circ\text{C}$	
$R_{\theta JC}$	Thermal Resistance-Junction to Case	0.42	$^\circ\text{C}/\text{W}$
$R_{\theta JA}^{(3)}$	Thermal Resistance-Junction to Ambient	62.5	$^\circ\text{C}/\text{W}$
<b>Drain-Source Avalanche Ratings</b>			
$E_{AS}^{(4)}$	Avalanche Energy, Single Pulsed	1640	mJ

**Electrical Characteristics (T<sub>C</sub>=25°C Unless Otherwise Noted)**

Symbol	Parameter	Test Condition	Rating			Unit
			Min.	Typ.	Max.	
<b>Static Characteristics</b>						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>DS</sub> =250μA	100			V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			1	μA
		T <sub>J</sub> =125°C			30	
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250μA	2	3	4	V
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±100	nA
R <sub>DS(ON)</sub> <sup>⑤</sup>	Drain-Source On-state Resistance	V <sub>GS</sub> =10V, I <sub>DS</sub> =40A		2	2.4	mΩ
		V <sub>GS</sub> =6V, I <sub>DS</sub> =20A		2.8	3.6	mΩ
<b>Diode Characteristics</b>						
V <sub>SD</sub> <sup>⑤</sup>	Diode Forward Voltage	I <sub>SD</sub> =40A, V <sub>GS</sub> =0V		0.83	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>SD</sub> =40A, dI <sub>SD</sub> /dt=100A/μs		77		ns
Q <sub>rr</sub>	Reverse Recovery Charge			171		nC
<b>Dynamic Characteristics</b> <sup>⑥</sup>						
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> =0V, V <sub>DS</sub> =0V, F=1MHz		2		Ω
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =50V, Frequency=200KHz		10800		pF
C <sub>oss</sub>	Output Capacitance			1370		
C <sub>rss</sub>	Reverse Transfer Capacitance			50		
t <sub>d(ON)</sub>	Turn-on Delay Time	V <sub>DD</sub> =50V, I <sub>DS</sub> =40A, V <sub>GEN</sub> =10V, R <sub>G</sub> =3Ω		37		ns
t <sub>r</sub>	Turn-on Rise Time			29		
t <sub>d(OFF)</sub>	Turn-off Delay Time			86		
t <sub>f</sub>	Turn-off Fall Time			43		
<b>Gate Charge Characteristics</b> <sup>⑥</sup>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>DS</sub> =40A		174		nC
Q <sub>gs</sub>	Gate-Source Charge			46		
Q <sub>gd</sub>	Gate-Drain Charge			46		

Notes: ①Pulse width limited by safe operating area.

②Calculated continuous current based on maximum allowable junction temperature. The package limitation current is 75A.

③When mounted on 1 inch square copper board, t≤10sec. The value in any given application depends on the user's specific board design.

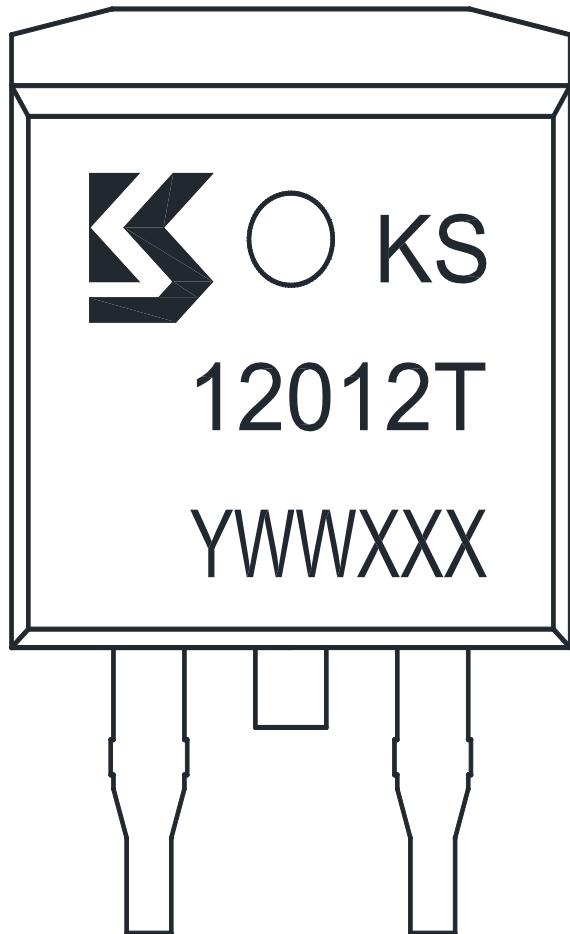
④Limited by T<sub>Jmax</sub>, Starting T<sub>J</sub> = 25°C, I<sub>ASmax</sub> = 81A, L=0.5mH, V<sub>DD</sub> = 48V, R<sub>G</sub> = 25Ω, V<sub>GS</sub>=10V.Part not recommended for use above this value.100% Final Test at I<sub>AS</sub>=56A, L=0.5mH.

⑤Pulse test;Pulse width≤300μs, duty cycle≤2%.

⑥Guaranteed by design, not subject to production testing.

**Ordering and Marking Information**

Device	Package	Packaging	Quantity	Reel Size	Tape width
KS12012GAT	TO-263	Tape&Reel	800	13"	24mm

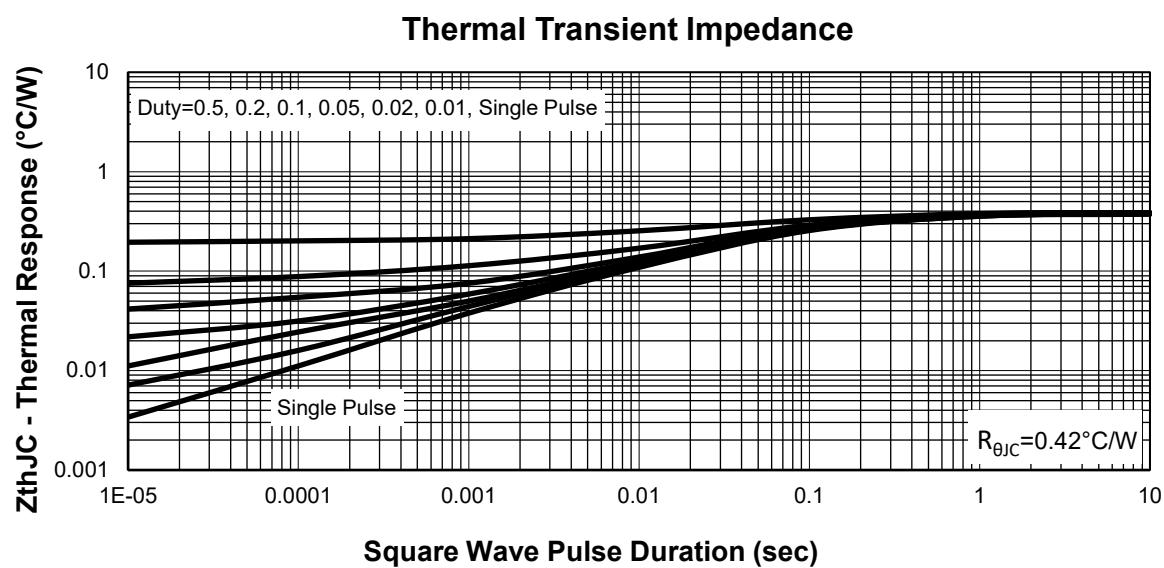
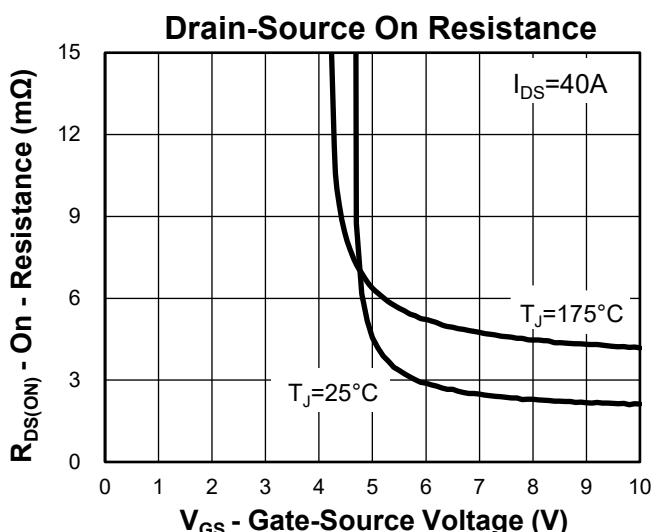
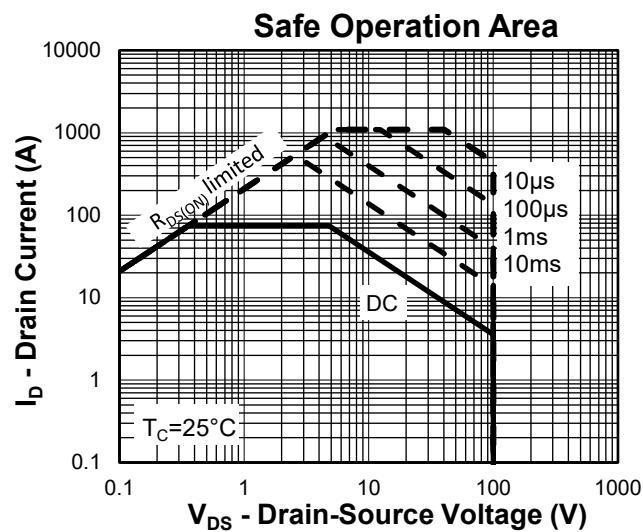
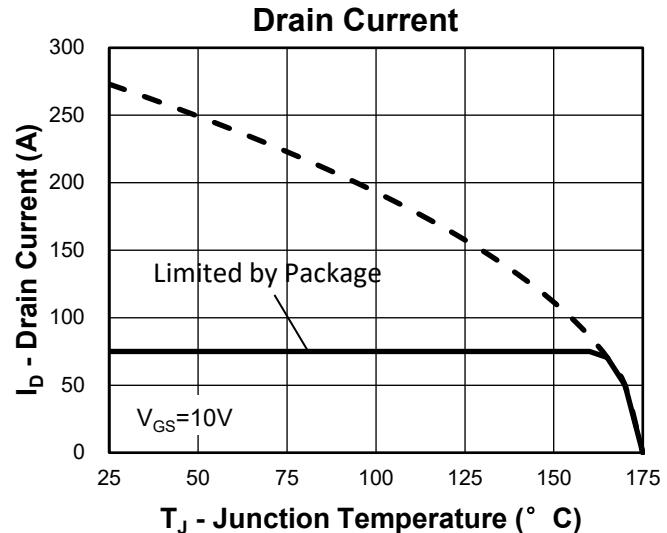
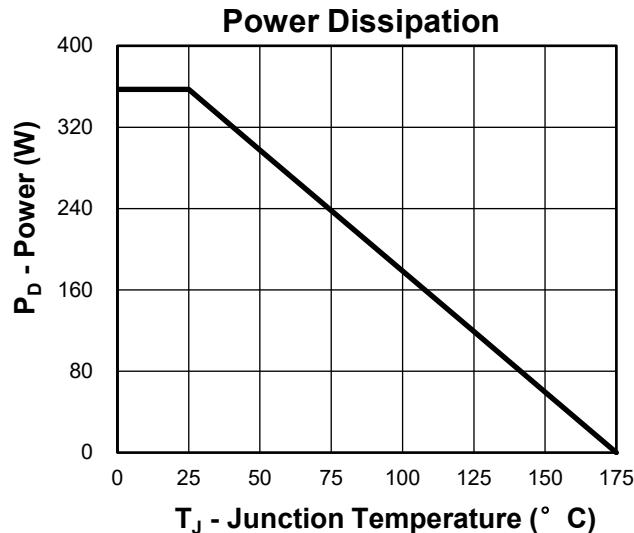


1st Line: Kwansemi LOGO, Kwansemi Code(KS)

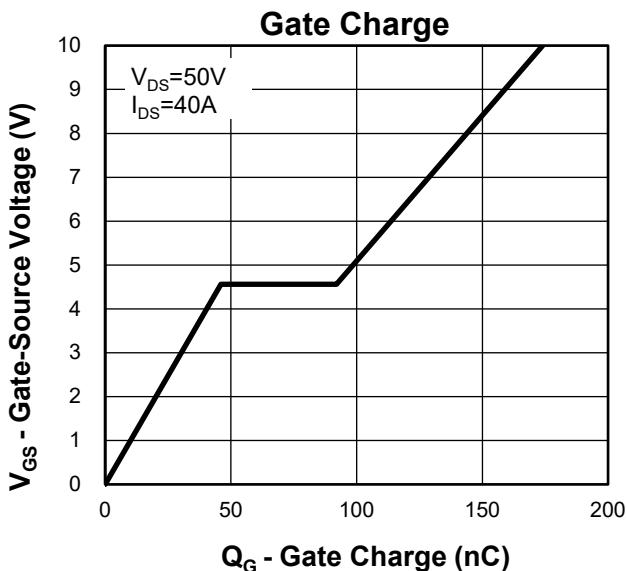
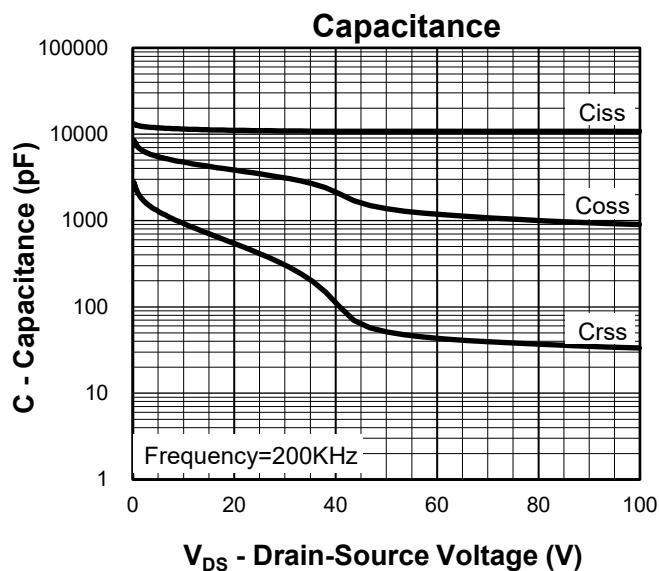
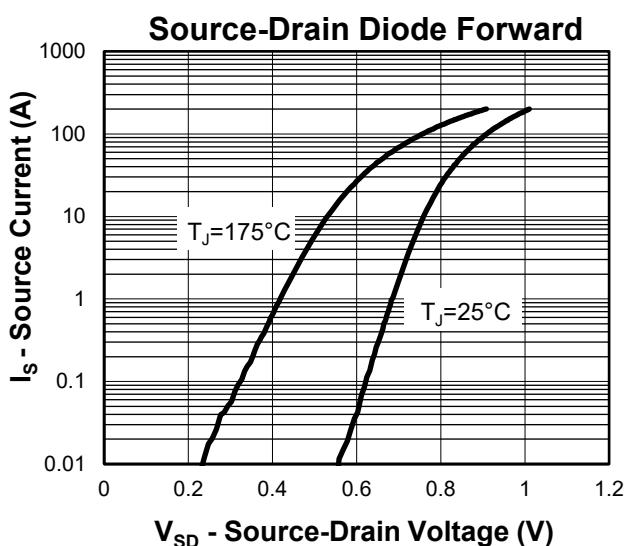
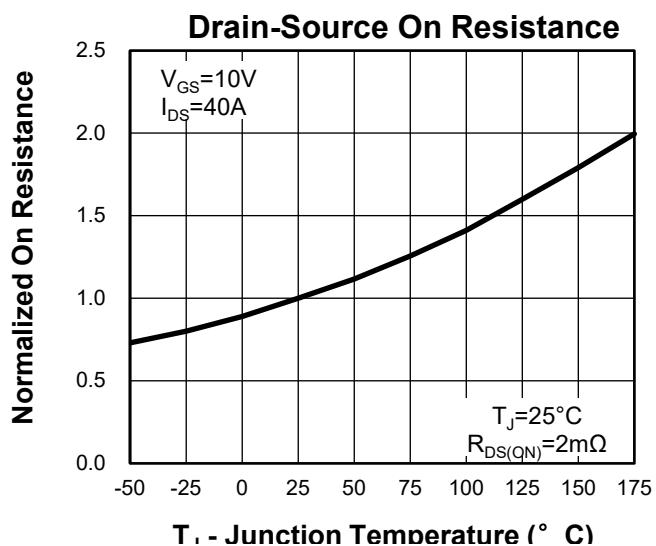
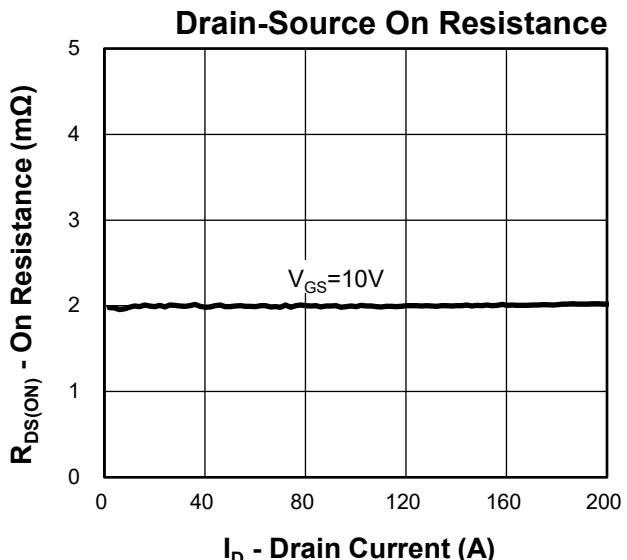
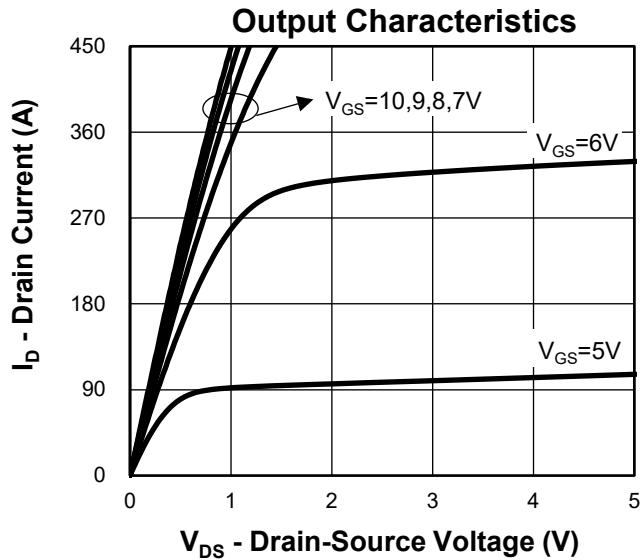
2nd Line: Part Number(12012T)

3rd Line: Lot Number(YWWXXX)

## Typical Characteristics

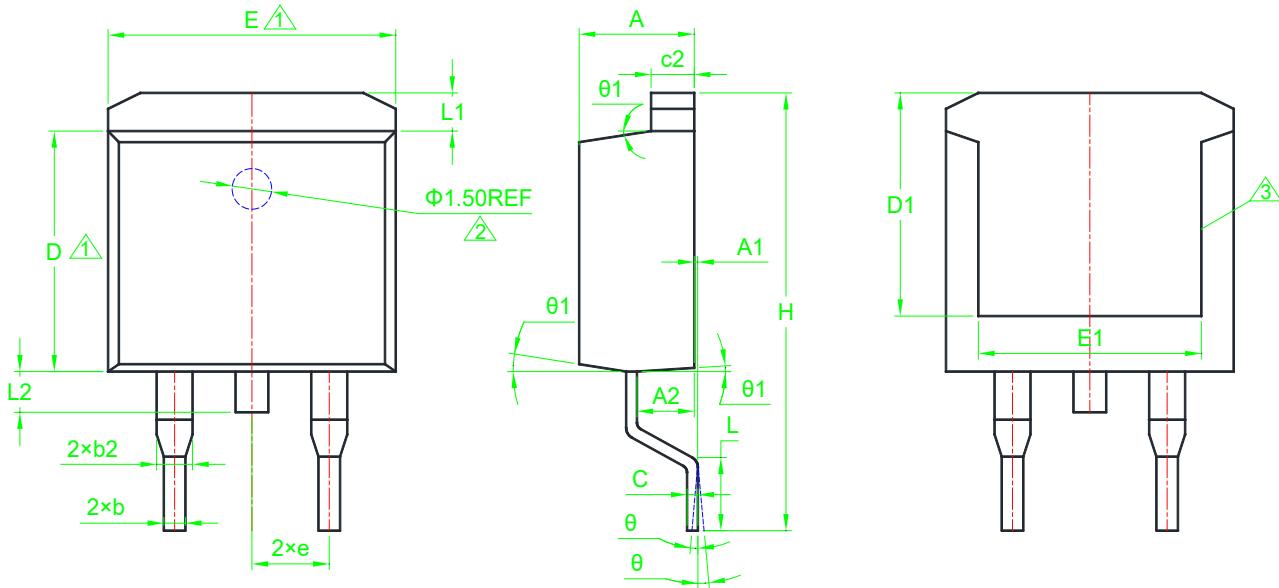


## Typical Characteristics



## Package Information

### TO-263



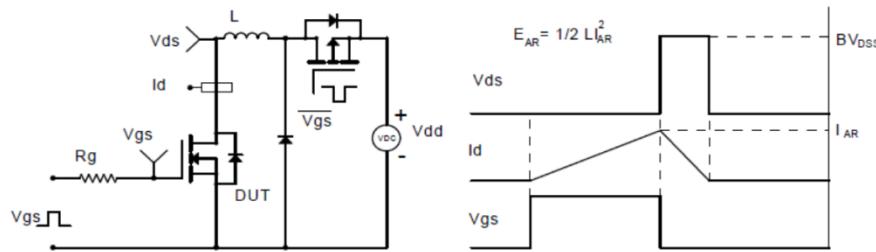
SYMBOL	MM			INCH			SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX		MIN	NOM	MAX	MIN	NOM	MAX
A	4.30	4.50	4.80	0.169	0.177	0.189	e	2.54BSC			0.100BSC		
A1	0.00	0.10	0.25	0.000	0.004	0.010	E	9.90	10.10	10.30	0.390	0.398	0.406
A2	2.20	*	2.80	0.087	*	0.110	E1	7.00	*	8.50	0.276	*	0.335
b	0.70	0.85	0.95	0.028	0.033	0.037	H	14.80	*	15.70	0.583	*	0.618
b2	1.15	*	1.47	0.045	*	0.058	L	2.10	*	2.79	0.083	*	0.110
c	0.38	*	0.65	0.015	*	0.026	L1	1.10	*	1.42	0.043	*	0.056
c2	1.20	1.30	1.40	0.047	0.051	0.055	L2	1.00	*	1.70	0.039	*	0.067
D	8.40	8.90	9.40	0.331	0.350	0.370	θ	0°	*	8°	0°	*	8°
D1	7.10	*	8.20	0.280	*	0.323	θ1	3°	*	9°	3°	*	9°

1 Dimensions D and E do not include mold flash protrusions or gate burrs.

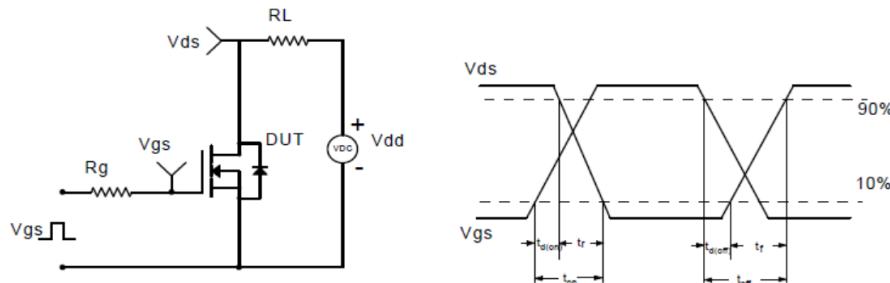
2 The existence and size of demolding hole are variable depending on mold.

3 The size and shape of exposed pad are variable depending on mold.

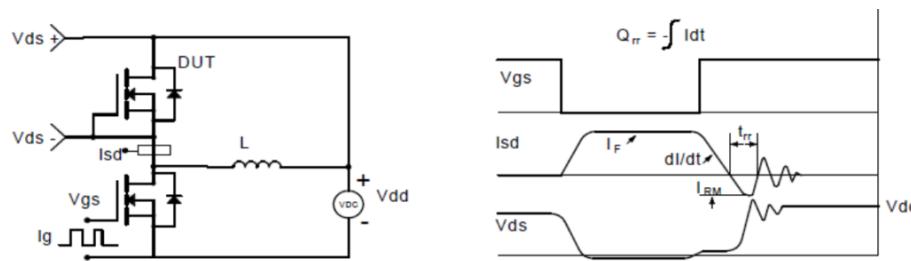
### Avalanche Test Circuit and Waveforms



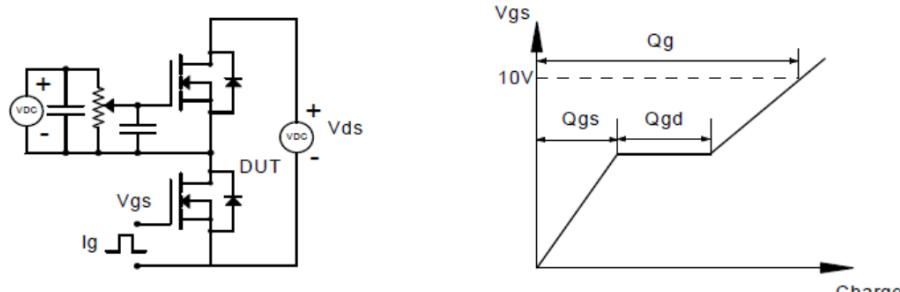
### Switching Time Test Circuit and Waveforms



### Diode Recovery Test Circuit and Waveforms



### Gate Charge Test Circuit and Waveform



### Customer Service

Kwansemi Semiconductor Co.,Ltd

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Web:[www.kwansemi.com](http://www.kwansemi.com)

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